Low Forward Voltage Trench-based Schottky Rectifier

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

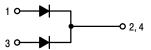
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



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PIN CONNECTIONS





MARKING DIAGRAM



TSV20H12G = Specific Device Code

A = Assembly Location

′ = Year

WW = Work Week

AKA = Polarity Designator

= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	120	V
Average Rectified Forward Current (Rated V_R , T_C = 124°C) (Rated V_R , T_C = 139°C)	Per device Per diode	I _{F(AV)}	20 10	А
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 122°C) (Rated V_R , Square Wave, 20 kHz, T_C = 137°C)	Per device Per diode	I _{FRM}	40 20	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	125	А
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating		nbol	Value	Unit
1 71	$\begin{array}{c} \text{ion-to-Case} & & & & & & & & & & $		1.7 50	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	٧ _F			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$		0.679	-	
(I _F = 10 A, T _J = 25°C)		0.931	1.03	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$		0.562	_	
$(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.653	0.71	
Maximum Instantaneous Reverse Current (Note 1)	I _R			
$(V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C})$		2.3		μΑ
$(V_R = 90 \text{ V}, T_J = 125^{\circ}\text{C})$		2.8		mA
(Rated dc Voltage, T _J = 25°C)		5.0	35	μΑ
(Rated dc Voltage, T _J = 125°C)		4.6	20	mA

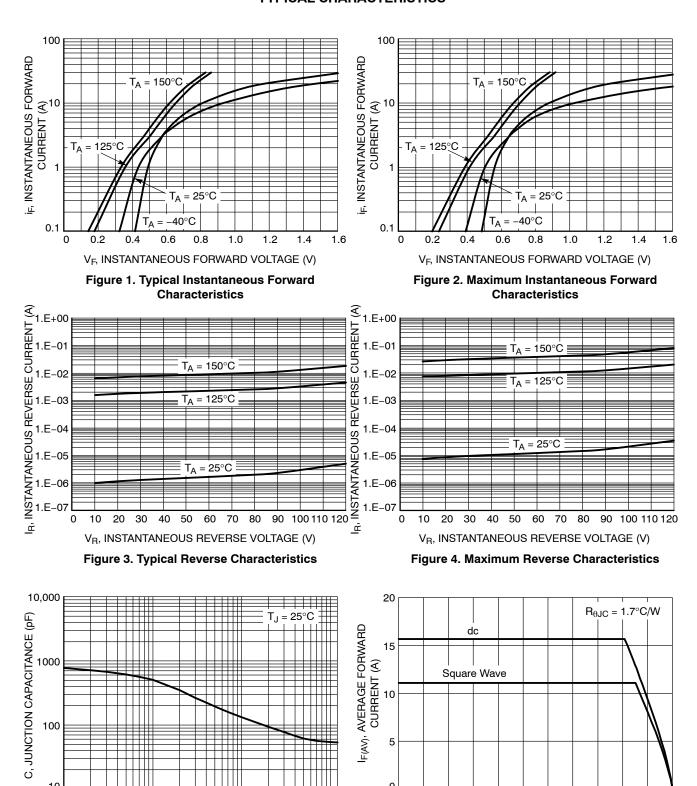
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Package	Shipping
NTSV20H120CTG	TO-220AB (Pb-Free)	50 Units / Rail

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

TYPICAL CHARACTERISTICS



 $\label{eq:VR} V_R,\, \text{REVERSE VOLTAGE (V)}$ Figure 5. Typical Junction Capacitance

0.1

 T_C , CASE TEMPERATURE (°C) Figure 6. Current Derating per Leg

100 110 120 130 140 150

90

100

50

40

TYPICAL CHARACTERISTICS

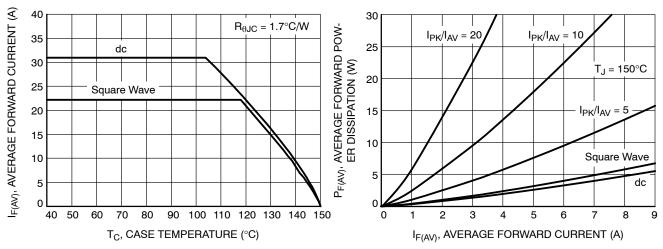


Figure 7. Current Derating, Device

Figure 8. Forward Power Dissipation

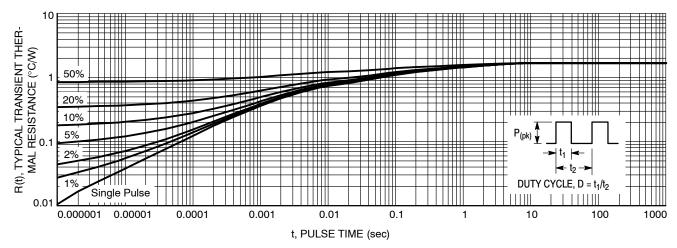
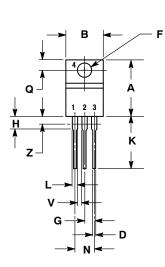
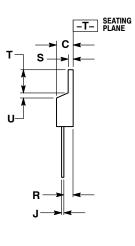


Figure 9. Typical Transient Thermal Response

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION Z DEFINES A ZONE WHERE ALL
 BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
ſ	0.014	0.024	0.36	0.61	
K	0.500	0.562	12.70	14.27	
٦	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 6: PIN 1. ANODE

- 2. CATHODE
- 3. ANODE
- CATHODE

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